Simbeor Application Note #2010_03, November 2010 © 2010 Simberian Inc.



Sensitivity of PCB Material Identification with GMS-Parameters to Variations in Test Fixtures



Simbeor®: Easy-to-Use, Efficient and Cost-Effective electromagnetic signal integrity software...

Property of Simberian Inc.

- Copyright © 2010 by Simberian Inc., All rights reserved.
 - THIS DOCUMENT IS CONFIDENTIAL AND PROPRIETARY TO SIMBERIAN INC. AND MAY NOT BE REPRODUCED, PUBLISHED OR DISCLOSED TO OTHERS WITHOUT PERMISSION OF SIMBERIAN INC.
- Simberian® and Simbeor® are registered trademarks of Simberian Inc.
 - Other product and company names mentioned in this presentation may be the trademarks of their respective owners.



Overview

- Introduction
- Identification of material parameters with Generalized Modal S-parameters
- Sensitivity of GMS-parameters to non-identity of cross-sections
- Sensitivity of GMS-parameters to non-identity of launches
- Effect of bends on GMS-parameters

Conclusion



Introduction

- Broadband dielectric and conductor models are the requisite foundation for performing meaningful electromagnetic verification of multi-gigabit interconnects
- Such model can be effectively identified with Generalized Modal Sparameters (GMS-parameters)
 - The method is the simplest possible and is based on fitting computed and measured GMS-parameters as outlined in:

Y. Shlepnev, A. Neves, T. Dagostino, S. McMorrow, Practical identification of dispersive dielectric models with generalized modal S-parameters for analysis of interconnects in 6-100 Gb/s applications – DesignCon 2010 – available at http://www.designcon.com/infovault/

- Measured S-parameters of 2 line segments are required to compute GMSparameters of line difference
- Transmission lines in both segments should have substantially identical cross-sections and connector or probe launches
- In reality, both cross-sections and transitions are not identical and test fixture may have discontinuities such as bends and vias
- This app note investigates sensitivity of the GMS-based method to variations in geometry of cross-sections and launches and presence of discontinuities in test fixtures
- □ Simbeor 2011 (64bit) built on Nov. 15th 2010 is used to generate the results



Overview

Introduction

- Identification of material parameters with Generalized Modal S-parameters (GMS)
- Sensitivity of GMS-parameters to non-identity of cross-sections
- Sensitivity of GMS-parameters to non-identity of launches
- Effect of bends on GMS-parameters

Conclusion



Material parameters identification with GMSparameters

- Measure S-parameters of two test fixtures with different length of line segments S1 and S2
- Transform S1 and S2 to the T-matrices T1 and T2, diagonalize the product of T1 and inversed T2 and compute GMS-parameters of the line difference
- Select material model and guess values of the model parameters
- Compute GMS-parameters of the line difference segment by solving Maxwell's equation for t-line cross-section (only propagation constants are needed)
- Adjust material parameters until computed GMS parameters fit measured GMS-parameters with the computed



Generalized Modal S-parameters (GMSparameters) for one-conductor line



Measure S-parameters of two test fixtures with line segments (no calibration is required)

S1 and T1 for line with length L1



□ S2 and T2 for line with length L2





Project1.solt 1p75 s2p.Simulation1, S[1,1]

Project1.solt_1p75_s2p.Simulation1, S[1,2]

Magnitude(S), [dB]

T1 and T2 matrices are scattering T-parameters (computed directly from S-parameters)



11/23/2010

Extract Generalized Modal T-parameters (GMT) and then GMS-Parameters



Identifying dielectrics by fitting GMSparameters



$$GMSc = \begin{bmatrix} 0 & \exp(-\Gamma \cdot dL) \\ \exp(-\Gamma \cdot dL) & 0 \end{bmatrix}$$

Fit measured data:

$$GMSm = \begin{bmatrix} 0 & T_{11} \\ T_{11} & 0 \end{bmatrix}$$

dLn1, Sm[In2(M1),In1(M1)]جنا Project1.Difference. Project1.1.75 inch segment mulation1, Sm[In2[M1],In1[M1]] Magnitude(S), [dB] Angle(S), [deg] Only 1 complex function! -100-200 -300 12.5 10 2.5 5 7.5 15 17.5 14 Nov 2010, 14:06:00, Simberian Inc. Frequency, [GHz]

- Measured GMS-parameters of the segment can be directly fitted with the calculated GMS-parameters for material parameters identification
- Phase or group delay can be used to identify DK and insertion loss to identify LT or conductor roughness!



The GMS-parameters technique is the simplest possible

- Needs un-calibrated measurements for 2 t-lines with any geometry of cross-section and transitions
 - No extraction of propagation constants (Gamma) from measured data (difficult, error-prone)
 - No de-embedding of connectors and launches (difficult, errorprone)
- Needs the simplest numerical model
 - Requires computation of only propagation constants
 - No 3D electromagnetic models of the transitions
- Minimal number of smooth complex functions to match
 - One parameter for single and two parameters for differential
 - All reflection and modal transformation parameters are exactly zeros



Overview

- Introduction
- Identification of material parameters with Generalized Modal S-parameters
- Sensitivity of GMS-parameters to non-identity of cross-sections
- Sensitivity of GMS-parameters to non-identity of launches
- Effect of bends on GMS-parameters

Conclusion



What if 2 lines used for identification have non-identical cross-sections?

Numerical experiment to investigate the consequences of the non-identity



Strip-line with W=7 ± 1 mil variation $20 \xrightarrow{Z, [mil]}$ $10 \xrightarrow{Z, [mil]}$ $10 \xrightarrow{Z,$

Models of the launches



From simulated S-parameters of 2 structures with varying strip widths we extract GMS-parameters of 2inch segment and compare it with the GMS-parameters of 2-inch segment computed directly

T-line parameters



Large variation of Zo and smaller variation of propagation constant parameters



Effect of strip width on S-parameters of the test fixtures



W±1 gives about ±0.5 dB difference in transmission coefficient at 50 GHz Phases are almost the same Reflection is mostly due to the reflection at the launches



Identical strip widths in test fixtures

GM transmission of 2-inch segment (green stars) match GM transmission extracted from S-parameters of 2 test fixtures (red circles)



The result is independent of actual width and launch construction as long as the widths and launches are identical in the test fixtures!



1 mil width difference in test fixtures

Magnitude of GM transmission of 2-inch segment (green stars) do not match GM transmission extracted from S-parameters of 2 test fixtures (brown and blue)



Smaller width in longer test fixture -> larger insertion loss Larger width in longer test fixture -> smaller insertion loss Identical phases – same identified DK!



1 mil width difference in test fixtures

Magnitude of GM transmission of 2-inch segment (green stars) do not match GM transmission extracted from S-parameters of 2 test fixtures (brown and blue) Less sensitive to variations in shorter test fixture



Smaller width in shorter test fixture -> smaller insertion loss Larger width in shorter test fixture -> larger insertion loss Identical phases – same identified DK!



2 mil width difference in test fixtures

Magnitude of GM transmission of 2-inch segment (green stars) do not match GM transmission extracted from S-parameters of 2 test fixtures (brown and blue)



Larger width in longer test fixture -> smaller insertion loss Smaller width in longer test fixture -> larger insertion loss Identical phases – same identified DK!



Effect of width variation on group delay

Magnitude of GM transmission of 2-inch segment (green stars) do not match GM transmission extracted from S-parameters of 2 test fixtures (brown and blue)



Group delay becomes not usable for DK identification with large strip width variations!



What if we use test fixture with variations of W for identification of dielectric model?



Difference in cross-section shape will have similar effect on loss identification

Real cross-sections may be not rectangular or trapezoidal!





- Difference in current distribution in simulated rectangular or trapezoidal conductor will produce different loss
 - This is the major source of errors in identification of loss parameters in case of low-loss dielectrics at high frequencies
 - Not a problem in case of regular FR-4 with LT~0.02



Overview

- Introduction
- Identification of material parameters with Generalized Modal S-parameters
- Sensitivity of GMS-parameters to non-identity of cross-sections
- Sensitivity of GMS-parameters to non-identity of launches
- Effect of bends on GMS-parameters

Conclusion



What if launches or connectors in test fixtures are not identical?

Numerical experiment to investigate the consequences of the non-identity





S-parameters of the launches

The larger the diameter of the pad, the larger the reflection |S11| and the smaller the transmission |S12| parameter





Effect of launch pad diameter on reflection from 8-inch test fixture

In case of the t-line impedance close to 50-Ohm, the envelop of the reflection parameters is mostly defined by the reflection from the transition





Effect of launch pad diameter on transmission through 8-inch test fixture

Reflective launch lead to substantial difference in the insertion loss |S12| of the test fixture



|S12| is not suitable for the material identification, even with relatively good launches!

Phases are practically identical

Group delays are substantially different due to reflections

The result is similar for the 6inch structure



GMS-parameters in case of identical launches

Extracted GM transmission parameters of 2-inch segment are independent of the launch geometry as long as all 4 launches on 2 test fixtures are identical

Launch with 8 mil pad:

Launch with 22 mil pad:



What if launches on 6-inch fixture are different from launches on 8-inch fixture?

- Magnitude of Generalized Modal transmission looks "noisy"
- Material identification may be possible only up to 20-25 GHz





What if launches on 6-inch fixture are different from launches on 8-inch fixture?

- Phase of Generalized Modal transmission looks OK up to 40 GHz
- Group Delay is "noisy" starting from about 10 GHz

Arg(GMS12)



Stars – 2-inch segment Blue line – launch T0 on 6-inch and T1 on 8-inch fixture



Another pair of launches

- Generalized Modal transmission looks "noisy"
- Material identification may be possible only up to 20-25 GHz



The smaller difference in the reflection loss, the smaller the noise!



Another pair of launches

- Phase of Generalized Modal transmission looks OK
- Group Delay may be usable up to 20 GHz



Arg(GMS12)

Stars – 2-inch segment Blue line – launch T1 on 6-inch and T2 on 8-inch fixture



Another pair of launches

- Generalized Modal transmission looks "noisy"
- Material identification may be possible only up to about 15-20 GHz



The larger the difference in the reflection loss, the larger the noise!



Worst pair of launches (most reflective)

- Generalized Modal transmission looks "noisy"
- Material identification may be possible only up to about 10-15 GHz



The larger the difference in the reflection loss, the larger the noise!



Worst pair of launches (most reflective)

- Phase becomes "noisy" above 30 GHz
- Group delay is usable only up to 5-10 GHz



Stars – 2-inch segment Blue line – launch T3 on 6-inch and T4 on 8-inch fixture



50

Example with acceptable difference in pad diameters



Difference of reflections from the launches should be less than 0.05 for material identification up to 50 GHz This measure is not practical – TDR may be used instead



Example with acceptable difference in pad diameters

- Phase is clean and can be used for identification up to 50 GHz
- Group Delay is usable up to 30-40 GHz

Arg(GMS12)



Stars – 2-inch segment Blue line – 15 mil pad on 6-inch and 13 mil on 8-inch fixture



TDR of the test fixture can provide measure of non-identity



The difference in the launch impedances should be less than 1 Ohm for material identification up to 50 GHz



Overview

- Introduction
- Identification of material parameters with Generalized Modal S-parameters
- Sensitivity of GMS-parameters to non-identity of cross-sections
- Sensitivity of GMS-parameters to non-identity of launches
- Effect of bends on GMS-parameters
- Conclusion



What if line segments in test fixtures are not straight?

Numerical experiment to investigate effect of bends



Instead of straight line try to use lines with multiple regular and chamfered bends (from 5 to 15 bends per test fixture)





Electromagnetic Solutions

09 Nov 2010, 12:39:19, Simberian Inc. 3D View Mode (press <E> to Edit).

From simulated S-parameters of 2 structures with multiple bends we extract GMS-parameters of 2-inch segment and compare it with the GMS-parameters of 2-inch segment computed directly

¥¥

S-parameters of the bend

- Very small reflection below -25 dB up to 40 GHz
- Small additional group delay
- IS12 is very close to 1



Almost negligible!?



Bend in 7-mil strip line (7 mil of

Test fixtures for the extraction







Red lines – 8 inch straight; Brown lines – 8 inch with 7 bends





Red lines – 8 inch straight; Green lines – 8 inch with 15 bends









Noise above 30 GHz and under-estimated angle and DK!





Small dips above 30 GHz and slightly under-estimated phase Matching number of bends may be good idea!





Larger dips above 25 GHz and under-estimated phase (and DK) Magnitude of dips is sensitive to total number of bends and phase is sensitive to the difference in the bend count!





Benchmark.SE Strip 2 inch.Simulation1, Sm[In1(M1),In2(M1)]



Group delay is smaller and more noisy for larger difference in the bend count

Simberian

tromagnetic Solutions

© 2010 Simberian Inc.

Y. [mil]

09 Nov 2010, 12:53:58, Simberian Inc. 3D View Mode (press <E> to Edit

20 -

What if we compensate bends with chamfers?

- Extremely small reflection below -30 dB up to 50 GHz!
- Small additional group delay
- IS12 is very close to 1



Negligible for sure?!



Chamfered bend in 7-mil strip



Red lines – 8 inch straight; Blue lines – 8 inch with 7 chamfered bends





Slightly smaller attenuation (lower LT) and under-estimated angle (lower DK)!





Ideal attenuation and slightly under-estimated angle (lower DK)



Effect of chamfered bends on group delay

- Y. [mi] 125-125-125--25
- About 6 ps difference in case of no bends in one test fixture (may lead to about 3% difference in identified DK)
- Less than 2 ps difference in case of 5 and 7 chamfered bends – acceptable for the extraction of DK (about 1% difference in identified DK)





Conclusion

- Overview of material parameters identification by fitting measured and computed GMS-parameters for single strip line is provided
- Sensitivity of the GMS-parameters method to variations in geometry of the test fixtures is investigated with numerical experiments
 - Small variations in strip width and shape in the test fixtures can cause over or under-estimation of extracted material loss parameters (LT, conductor and roughness parameters)
 - Small variations in geometry of connectors or launches in test fixtures can cause "noise" in GMS-parameters at high frequencies – TDR may be used to qualify test fixtures
 - Multiple bends or other discontinuities can cause noise in GMSparameters and under-estimation of dielectric constant
 - Matching number of bends and chamfering reduces the extraction errors
- Setting up all simulations and model building with Simbeor took about 3 hours



Solutions and contact

Simbeor solution files are in the database <u>http://kb.simberian.com/SimbeorExamples.php</u> (keyword 2010_03) It contains all electromagnetic models and linear circuit analysis both in frequency and time domains

- Send questions and comments to
 - General: info@simberian.com
 - Sales: <u>sales@simberian.com</u>
 - Support: <u>support@simberian.com</u>
- □ Web site <u>www.simberian.com</u>



S-matrices and T-matrices

Same number of ports on the left and right side of multiport



 $T_{1,2} = S_{11} \cdot S_{21}^{-1}$

 $T_{22} = S_{21}^{-1}$

 $T_{2,1} = -S_{2,1}^{-1} \cdot S_{2,2}$

 $T_{1.1} = S_{2.1} - S_{1.1} \cdot S_{2.1}^{-1} \cdot S_{2.2}$

$$\begin{vmatrix} \overline{b}_1 \\ \overline{a}_1 \end{vmatrix} = \begin{bmatrix} T_{1,1} & T_{1,2} \\ T_{2,1} & T_{2,2} \end{bmatrix} \cdot \begin{vmatrix} \overline{a}_2 \\ \overline{b}_2 \end{vmatrix}$$

 $S_{1,1} = T_{1,2} \cdot T_{2,2}^{-1}$ $S_{1,2} = T_{1,1} - T_{1,2} \cdot T_{2,2}^{-1} \cdot T_{2,1}$

 $S_{2,1} = T_{2,2}^{-1}$

 $S_{22} = -T_{22}^{-1} \cdot T_{21}$

Cascading of 2 multiports described with Sparameters require solving a linear system

Cascading of 2 multiports described with Tparameters is simple product of two T-matrices

All elements are scalars in case of 2-ports (single-ended lines) or matrices in case of multi-conductor lines (differential)

See more in Carlin, Giordano, Network Theory, An Introduction to Reciprocal and Non-Reciprocal Circuits, 1964 Conversion can be generalized for arbitrary number of ports on the left and right

